INTEGRATED CIRCUITS



Product data Supersedes data of 2003 Apr 30

2003 Jul 30





SA57000-XX

GENERAL DESCRIPTION

The CapFREETM SA57000 is the first in a new family of unique low dropout regulators. It needs no external capacitors, offers a low output noise voltage of 30 μ V_{RMS}, and an ultra-low dropout voltage of 55 mV @ 50 mA output current. To accommodate high density layouts, it is packaged in the small footprint 5 leaded SOT23-5 (SO5) and a 5-bump Wafer Level Chip-Scale package (WL-CSP5). It is ideal for all portable and cellular phone applications.

Additional features include power and thermal shutdown, output current limitation, power OK status, thermal warning, and external logic-controlled on-off via the PWRON pin.

FEATURES

- CapFREE: No output capacitor needed, stable for all capacitive loads, regardless of ESR
- 5 leaded SOT23-5 (SO5) and Wafer Level Chip-Scale (WL-CSP5) packages
- Low 30 μ V_{RMS} noise without noise bypass capacitor
- Preset output voltages to 2.5 V, 2.8 V, 2.9 V, 3.0 V, 3.1 V, 3.3 V and 3.6 V; other voltages available upon request. 2% output voltage accuracy
- 150 mA maximum output current with current limitation



- Typical dropout voltage 55 mV @ 50 mA output current
- 85 µA typical ground current
- Shut-down (standby) current < 1 μA
- Thermal-overload and short-circuit protection
- PWROK pin: both power status and thermal warning indicator
- PWRON pin offers logic-controlled shutdown
- Maximum line regulation: 0.1%/V
- Maximum load regulation: 0.02%/mA.

APPLICATIONS

- Cordless and mobile phones
- Industrial and medical equipment
- Other battery-powered equipment.



SIMPLIFIED SYSTEM DIAGRAM

Figure 1. Simplified system diagram.

CapFREE is a trademark of Philips Electronics North America Corporation.

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ORDERING INFORMATION

TYPE NUMBER	PACKAGE	TEMPERATURE			
	NAME	DESCRIPTION VERSION		RANGE	
SA57000- XX D SOT23-5, SO5		plastic small outline package; 5 leads (see dimensional drawing)	SOT680-1	–40 to +85 °C	
SA57000- XX UK	57000-XXUK WL-CSP5 wafer level, chip-scale package; 5 bumps (see dimensional drawing)		–40 to +85 °C		

NOTE:

The device has seven voltage output options, indicated by the $\boldsymbol{X}\boldsymbol{X}$ on the Type Number.

ХХ	VOLTAGE (Typical)
25	2.5 V
28	2.8 V
29	2.9 V
30	3.0 V
31	3.1 V
33	3.3 V
36	3.6 V

PIN CONFIGURATION



Figure 2. Pin configurations.

PIN DESCRIPTION

PIN	BALL	SYMBOL	DESCRIPTION	
1	A1	V _{IN}	Regulator input. V _{OUT(nom)} + 0.5 V to 6.5 V. No bypass capacitor required.	
2	B2	GND	Ground.	
3	C1	PWRON	Power-on input. Active-HIGH. A logic LOW powers down the regulator. The shutdown quiescent current is typically 50 nA. Connect to V _{IN} for manual operation.	
4	C3	PWROK	Power OK indicator, including thermal warning. Connect a 10 k Ω resistor between PWROK and V _{OUT} . Active-LOW open-drain output indicates an out-of-regulation condition when power falls typically 6% below VOUT(nom), or thermal warning (trips at 127 °C ± 2 °C).	
5	A3	V _{OUT}	Regulator output. Sources up to 150 mA. No bypass capacitors required.	

Marking code

Each device is marked with a four letter code. The first three letters designate the product. The fourth, represented by an 'x', designates the date tracking code.

Part	Marking
SA57000-25UK, SA57000-25D	ABKx
SA57000-28UK, SA57000-28D	ABLx
SA57000-29UK, SA57000-29D	ABXx
SA57000-30UK, SA57000-30D	ABMx
SA57000-31UK, SA57000-31D	ABYx
SA57000-33UK, SA57000-33D	ABNx
SA57000-36UK, SA57000-36D	ABPx

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MAXIMUM RATINGS

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{IN}	V _{IN} to GND voltage		-0.3	6.5	V _{DC}
V _{PWRON}	PWRON to GND voltage		-0.3	6.5	V _{DC}
V _{OUT}	OUT to GND voltage		-0.3	V _{IN} + 0.3	V _{DC}
T _{amb}	Operating ambient temperature		-40	+85	°C
Tj	Junction temperature		-	+125	°C
T _{stg}	Storage temperature		-65	+160	°C
Р	Power dissipation (Derating factor above 25 °C)	T _{amb} = 25 °C	-	637	mW
R _{th(j-a)}	Thermal resistance from junction to ambient		-	140	°C/W

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CHARACTERISTICS

 $V_{IN} = V_{OUT(nom)} + 0.5 V.$ (Note 1.)

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{IN}	input voltage		V _{OUT(nom)}	_	6.5	V
	output voltage accuracy ²	I _{OUT} = 1 mA				
		$T_{amb} = +25 \ ^{\circ}C$	-	±1	-	%
		–40 °C ≤ T _{amb} ≤ +85 °C	-2.0	-	2.0	%
I _{LIM}	current limit		160	300	-	mA
l _Q	ground pin current	I _{OUT} = 1 mA to 150 mA	-	85	150	μΑ
	dropout voltage ³	I _{OUT} = 1 mA	-	1	-	mV
		I _{OUT} = 50 mA	-	55	120	mV
		I _{OUT} = 150 mA	-	165	-	mV
ΔV_{LNR}	line regulation	$V_{IN} = (V_{OUT} + 0.1 \text{ V}) \text{ to } 5.5 \text{ V}; I_{OUT} = 20 \text{ mA}$	-	-	0.1	%/V
ΔV_{LDR}	load regulation	I _{OUT} = 1 mA to 150 mA	-	0.01	0.02	%/mA
e _n	output voltage noise	f = 10 Hz to 100 kHz, C_{OUT} = 10 μ F	-	30	-	μV_{RMS}
Shutdown	•	•			•	•
V _{IH}	PWRON input threshold (HIGH ON-state)	$V_{\text{IN}} \rightarrow V_{\text{OUT(nom)}} \rightarrow 6.5 \text{ V}$	$0.7 imes V_{IN}$	_	_	V
V _{IL}	PWRON input threshold (HIGH ON-state)	$V_{\text{IN}} \rightarrow V_{\text{OUT(nom)}} \rightarrow 6.5 \text{ V}$	-	_	$0.3 imes V_{IN}$	V
I _{PWRON}	PWRON input bias current	V _{PWRON} = V _{IN}				
		T _{amb} = +25 °C	-	0.01	1	μΑ
		T _{amb} = +85 °C	-	0.05	-	μΑ
I _{Q(SHDN)}	shutdown supply current	V _{OUT} = 0 V				
		$T_{amb} = +25 \circ C$	-	0.05	1	μΑ
		T _{amb} = +85 °C	-	0.2	1	μΑ
t _{PWRON}	power-on start-up time ⁴	$I_{OUT} = 1 \text{ mA}, C_{OUT} = 100 \text{ nF}$				
		$T_{amb} = +25 \text{ °C}$	-	25 35	100	μs
Thormolo	votaction (Nota 2)	$T_{amb} = -40$ to +85 °C	-	35	200	μs
-	rotection (Note 2)					
T _{SHDN}	thermal shut-down temperature		-	144	-	°C
ΔT _{SHDN}	thermal shut-down hysteresis		-	13	-	°C
PWROK ou	utput (power and temperature OK	.) (Note 2)				
	PWROK trip temperature		-	127	-	°C
	PWROK trip temperature hysteresis		-	12	-	°C
	PWROK trip as percentage of $V_{OUT(nom)}$		-3.5	-6	-8	%
	PWROK hysteresis as percentage of V _{OUT(nom)}		-	2	-	%
	PWROK output (when tripped)	I _{SINK} = 0.5 mA	-	0.1	0.4	V

NOTES:

1. Limits are production tested at Tamb = +25 °C. All devices are 100% production tested at 25 °C. Limits over the operating tempreature are 2. Accuracy ±2 °C over temperature range guaranteed by design and characterization.
3. The dropout voltage is defined as V_{IN} - V_{OUT} where V_{OUT} is 100 mV below the value of V_{OUT} for V_{IN} = V_{OUT} + 0.5 V.
4. Time needed for V_{OUT} to reach 95% of V_{OUT(nom)}.

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TYPCIAL PERFORMANCE CURVES

Measurements taken with the SA57000-33 (3.3 volt output).



Figure 3. Output voltage versus temperature.



Figure 5. Ground current versus input voltage (no load).



Figure 7. T_j versus $V_{IN} - V_{OUT}$ for 3 output currents.



Figure 4. Ground current versus temperature.



Figure 6. Ground current versus input voltage with load.



Figure 8. Maximum I_{OUT} versus $V_{IN} - V_{OUT}$.

with thermal protection

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70 60 50 40 PSRR (dB) $C_{OUT} = 1 \ \mu F$ 30 20 10 COUT = 0 μF 0 0.1 10 1000 100000 FREQUENCY (Hz) SL01873

CapFREE™ 150 mA, low-noise, low dropout regulator

Figure 9. Power supply rejection ratio versus frequency.



Figure 11. Output noise spectral density versus frequency.



Figure 10. Output noise versus load current.



Figure 12. Lifetime versus $V_{IN} - V_{OUT}$ for 3 output currents.

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TECHNICAL DESCRIPTION

General discussion

The SA57000-XX is a low dropout, low-quiescent current linear regulator designed primarily for battery-powered applications and stabilizes with or without input/output capacitors. The device delivers up to 150 mA and is available with preset output voltages of 2.5 V, 2.8 V, 2.9 V, 3.0 V, 3.1 V, 3.3 V, and 3.6 V for both SOT 23-5 and WL-CSP packages.

The 1.23 band-gap reference is connected to the error amplifier's inverting input. The error amplifier compares this reference with the feedback voltage and amplifies the difference. If the feedback voltage is lower than the reference voltage, the pass-transistor gate is pulled lower, which allows more current to pass to the output. The output voltage is fed back through an internal resistor voltage divider connected to the V_{OUT} pin.

Band-gap

The band-gap circuitry generates a temperature independent voltage by properly adding two voltages with negative and positive temperature coefficient. The band-gap voltage is typically 1.23 volts with a temperature variation of 5 mV over the temperature range from -40 °C to +125 °C.

Low-pass filter

Low-pass filter is basically an RC filter with a low cut-off frequency. **No external capacitor is used**. There is one comparator, which turns on the bypass paths to charge or discharge the capacitor if the output of the filter is higher or lower than the band-gap voltage by a specified amount.

Output amplifier

The output amplifier is a folded-cascode PMOS amplifier which controls the gate of the output transistor and sources the load current. A portion of the output voltage is compared to the reference voltage and a constant voltage is maintained at output. The output is also monitored by a comparator which trips PWROK if the output voltage falls below the nominal output level by a specified amount due to low battery condition or any other reason. The current limiter circuit monitors the output current and limits the load current to a certain value to avoid any damage due to short circuit.

Bias circuit

The bias block provides bias currents and voltages for the other blocks. It has a self start-up circuit and it can establish the bias currents and voltages very fast.

Temperature sensor

The temperature sensor block monitors the die temperature and flags PWROK when the temperature crosses 125 °C. If the die temperature goes beyond 144 °C typical value, the output amplifier is shut down. Both the temperatures corresponding to Power-OK or shutdown have a hysteresis of 13 °C.

ESD protection

The standard ESD blocks protect the CMOS circuit against electrostatic discharge (ESD).

PRWROK output

PWROK goes LOW when the output voltage goes out of regulation as during drop-out, current limit or thermal shutdown. PowerOK is an open-drain N-channel MOSFET. To obtain a logic-level output, connect a 10 k Ω pull-up resistor from PWROK pin to V_{OUT} pin. To minimize current consumption, make this resistor as large as practical. A 100 k Ω resistor works well for most applications. The PowerOK is not active during shutdown.

Current limit

The SA57000-XX includes a current limiter that monitors and controls the pass transistor's gate voltage, limiting the output current to 300 mA typical value. For design purposes, consider the current limit to be 160 mA minimum value. The output can be shorted to ground for an indefinite period of time without damaging the part.

Thermal-overload protection

When the junction temperature exceeds $T_j = 144$ °C typical value, the thermal sensor signals the shutdown logic, turning off the output amplifier and allowing the die to cool. The thermal sensor will turn the output amplifier on again after the die's junction temperature decreases by 13 °C hysteresis value, resulting in a pulsed output during continuous thermal overload conditions.

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TIMING DIAGRAM



Figure 13. Timing diagram.

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WL-CSP5: wafer level, chip-scale package; 5 bumps



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TAPE & REEL IN WAFER LEVEL CHIP-SCALE PACKAGE



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PACKING METHOD



Figure 14. Tape and reel packing method

Product data

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REVISION HISTORY

Rev	Date	Description	
_6	20030730	Product data (9397 750 11836); ECN 853-2265 29874 of 28 July 2003; supersedes data of 2003 Apr 30 (9397 750 11452). Modifications: • Add "Marking code" table to page 3.	
5	20030430	Product data (9397 750 11452); ECN 853-2265 29874 of 29 April 2003;	
_5	20030430	supersedes data of 2003 Apr 01 (9397 750 10539).	
_4	20030401	Product data (9397 750 10539); ECN 853–2265 29019 of 07 October 2002; supersedes data of 2001 Oct 16 (9397 750 08983).	
_3	20011016	Product data (9397 750 08983); ECN 853-2265 27240 of 16 October 2001.	
_2	20010827	Product data (9397 750 08722); ECN 853–2265 26991 of 27 August 2001.	
_1	20010712	Product data (9397 750 08564); ECN 853-2265 26703 of 12 July 2001.	

Product data

Data sheet status

Level	Data sheet status ^[1]	Product status ^{[2] [3]}	Definitions
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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